

54F/74F192 **Up/Down Decade Counter** with Separate Up/Down Clocks

General Description

The 'F192 is an up/down BCD decade (8421) counter. Separate Count Up and Count Down Clocks are used, and in either counting mode the circuits operate synchronously. The outputs change state synchronously with the LOW-to-HIGH transitions on the clock inputs.

Separate Terminal Count Up and Terminal Count Down outputs are used as the clocks for a subsequent stage without extra logic, thus simplifying multistage counter designs. Individual preset inputs allow the circuit to be used as a programmable counter. Both the Parallel Load (PL) and the Master Reset (MR) inputs asynchronously override the clocks.

Features

■ Guaranteed 4000V minimum ESD protection

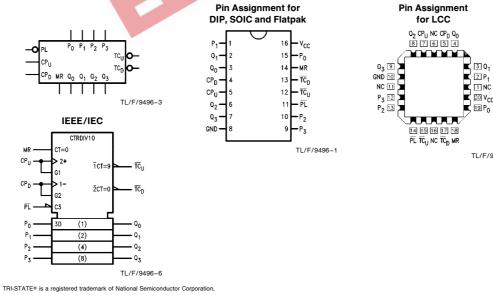
Commercial	Military	Package Number	Package Description		
74F192PC		N16E	16-Lead (0.300" Wide) Molded Dual-In-Line		
	54F192DM (Note 2)	J16A	16-Lead Ceramic Dual-In-Line		
74F192SC (Note 1)		M16A	16-Lead (0.150" Wide) Molded Small Outline, JEDEC		
74F192SJ (Note 1)		M16D	16-Lead (0.300" Wide) Molded Small Outline, EIAJ		
	54F192FM (Note 2)	W16A	16-Lead Cerpack		
	54F192LM (Note 2)	E20A	20-Lead Ceramic Leadless Chip Carrier, Type C		

Note 1: Devices also available in 13" reel. Use suffix = SCX and SJX.

Note 2: Military grade device with environmental and burn-in processing. Use suffix = DMQB, FMQB and LMQB.

Logic Symbols

Connection Diagrams



2 20 ∨_{CC}

TL/F/9496-2

Unit Loading/Fan Out

		54F/74F			
Pin Names	Description	U.L. HIGH/LOW	Input I _{IH} /I _{IL} Output I _{OH} /I _{OL}		
CPU	Count Up Clock Input (Active Rising Edge)	1.0/3.0	20 μA/ – 1.8 mA		
CPD	Count Down Clock Input (Active Rising Edge)	1.0/3.0	20 μA/ – 1.8 mA		
MR	Asynchronous Master Reset Input (Active HIGH)	1.0/1.0	20 μA/ – 0.6 mA		
PL	Asynchronous Parallel Load Input (Active LOW)	1.0/1.0	20 μA/ – 0.6 mA		
P ₀ -P ₃	Parallel Data Inputs	1.0/1.0	20 μA/ – 0.6 mA		
$Q_0 - Q_3$	Flip-Flop Outputs	50/33.3	-1 mA/20 mA		
TCD	Terminal Count Down (Borrow) Output (Active LOW)	50/33.3	-1 mA/20 mA		
TCU	Terminal Count Up (Carry) Output (Active LOW)	50/33.3	-1 mA/20 mA		

Functional Description

The 'F192 is an asynchronously presettable decade counter. It contains four edge-triggered flip-flops, with internal gating and steering logic to provide master reset, individual preset, count up and count down operations.

A LOW-to-HIGH transition on the CP input to each flip-flop causes the output to change state. Synchronous switching, as opposed to ripple counting, is achieved by driving the steering gates of all stages from a common Count Up line and a common Count Down line, thereby causing all state changes to be initiated simultaneously. A LOW-to-HIGH transition on the Count Up input will advance the count by one; a similar transition on the Count Down input will decrease the count by one. While counting with one clock input, the other should be held HIGH, as indicated in the Function Table. Otherwise, the circuit will either count by twos or not at all, depending on the state of the first flip-flop, which cannot toggle as long as either clock input is LOW.

The Terminal Count Up (\overline{TC}_U) and Terminal Count Down (TCD) outputs are normally HIGH. When the circuit has reached the maximum count state 9, the next HIGH-to-LOW transition of the Count Up Clock will cause TCU to go LOW. $\overline{\text{TC}}_{\text{U}}$ will stay LOW until CP $_{\text{U}}$ goes HIGH again, thus effectively repeating the Count Up Clock, but delayed by two gate delays. Similarly, the $\overline{\text{TC}}_{D}$ output will go LOW when the circuit is in the zero state and the Count Down Clock goes LOW. Since the TC outputs repeat the clock waveforms, they can be used as the clock input signals to the next higher order circuit in a multistage counter.

$$\begin{aligned} & \overline{TC}_U = Q_0 \bullet Q_3 \bullet \overline{CP}_U \\ \overline{TC}_D = & \overline{Q}_0 \bullet \overline{Q}_1 \bullet \overline{Q}_2 \bullet \overline{Q}_3 \bullet \overline{CP}_D \end{aligned}$$

The 'F192 has an asynchronous parallel load capability permitting the counter to be preset. When the Parallel Load (PL) and the Master Reset (MR) inputs are LOW, information present on the Parallel Data input (P0-P3) is loaded into the counter and appears on the outputs regardless of the conditions of the clock inputs. A HIGH signal on the Master Reset input will disable the preset gates, override both clock inputs, and latch each Q output in the LOW state. If one of the clock inputs is LOW during and after a reset or

load operation, the next LOW-to-HIGH transition of that clock will be interpreted as a legitimate signal and will be counted.

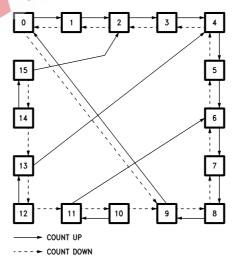
Function Table

MR	PL	CPU	CPD	Mode
Н	X	Х	x 🦪	Reset (Asyn.)
L	L	X	X	Preset (Asyn.)
L	Н	H. *	H	No Change
L	Н		Н 🥒	Count Up
L	H.	X H		Count Down

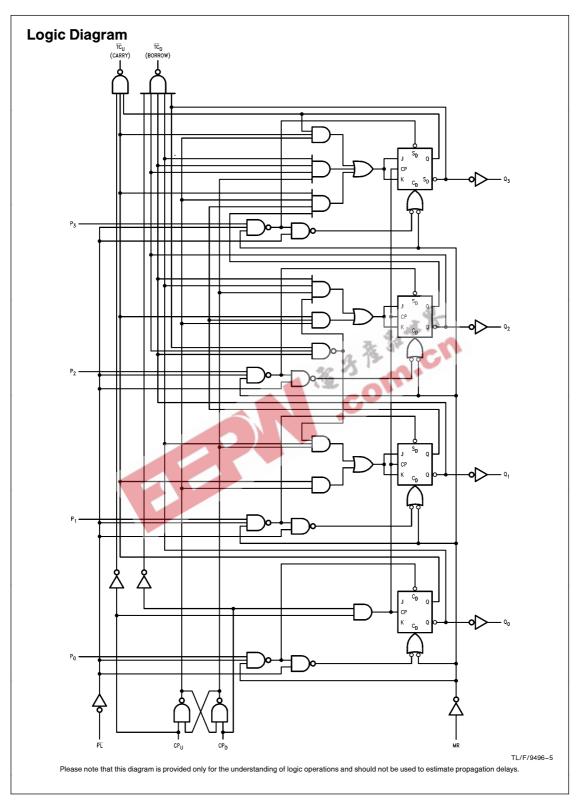
HIGH Voltage Leve LOW Voltage Level

LOW-to-HIGH Clock Transition

State Diagram



TI /F/9496-4



Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

 $\begin{array}{lll} \mbox{Storage Temperature} & -65^{\circ}\mbox{C to} + 150^{\circ}\mbox{C} \\ \mbox{Ambient Temperature under Bias} & -55^{\circ}\mbox{C to} + 125^{\circ}\mbox{C} \\ \mbox{Junction Temperature under Bias} & -55^{\circ}\mbox{C to} + 175^{\circ}\mbox{C} \\ \mbox{Plastic} & -55^{\circ}\mbox{C to} + 150^{\circ}\mbox{C} \\ \end{array}$

 $\begin{array}{lll} \text{V}_{\text{CC}} \text{ Pin Potential to} & & & \\ \text{Ground Pin} & & -0.5 \text{V to} + 7.0 \text{V} \\ \text{Input Voltage (Note 2)} & & -0.5 \text{V to} + 7.0 \text{V} \\ \text{Input Current (Note 2)} & & -30 \text{ mA to} + 5.0 \text{ mA} \end{array}$

Voltage Applied to Output in HIGH State (with V_{CC} = 0V)

 $\begin{array}{lll} & & & & & & & \\ \text{Standard Output} & & & & & & \\ \text{TRI-STATE} \bullet & \text{Output} & & & & & \\ & & & & & & & \\ \end{array}$

Current Applied to Output

in LOW State (Max) twice the rated I_{OL} (mA)

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

Recommended Operating Conditions

Free Air Ambient Temperature

Military $-55^{\circ}\text{C to} + 125^{\circ}\text{C}$ Commercial $0^{\circ}\text{C to} + 70^{\circ}\text{C}$

Supply Voltage

Military +4.5V to +5.5V Commercial +4.5V to +5.5V

DC Electrical Characteristics

Symbol	Parameter		54F/74F			Units	Vcc	Conditions	
Symbol	raiaille	tei	Min	Тур	Max	omits 4	VCC	Conditions	
V _{IH}	Input HIGH Voltage		2.0			V	' .	Recognized as a HIGH Signal	
V _{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal	
V _{CD}	Input Clamp Diode Vo	oltage		4 T	-1.2	V	Min	$I_{\text{IN}} = -18 \text{ mA}$	
V _{OH}	Output HIGH Voltage	54F 10% V _{CC} 74F 10% V _{CC} 74F 5% V _{CC}	2.5 2.5 2.7			٧	Min	$I_{OH} = -1 \text{ mA}$ $I_{OH} = -1 \text{ mA}$ $I_{OH} = -1 \text{ mA}$	
V _{OL}	Output LOW Voltage	54F 10% V _{CC} 74F 10% V _{CC}			0.5 0.5	٧	Min	I _{OL} = 20 mA I _{OL} = 20 mA	
l _{IH}	Input HIGH Current	54F 74F			20.0 5.0	μΑ	Max	$V_{IN} = 2.7V$	
I _{BVI}	Input HIGH Current Breakdown Test	54F 74F			100 7.0	μΑ	Max	V _{IN} = 7.0V	
I _{CEX}	Output HIGH Leakage Current	54F 74F			250 50	μΑ	Max	$V_{OUT} = V_{CC}$	
V_{ID}	Input Leakage Test	74F	4.75			٧	0.0	$I_{\text{ID}} = 1.9 \mu\text{A}$ All Other Pins Grounded	
I _{OD}	Output Leakage Circuit Current	74F			3.75	μΑ	0.0	V _{IOD} = 150 mV All Other Pins Grounded	
I _{IL}	Input LOW Current				-0.6 -1.8	mA	Max	$V_{IN} = 0.5V$, Except CP_u , CP_D $V_{IN} = 0.5V$, CP_u , CP_D	
I _{OS}	Output Short-Circuit C	Current	-60		-150	mA	Max	V _{OUT} = 0V	
I _{CCL}	Power Supply Current	t		38	55	mA	Max	$V_O = LOW$	

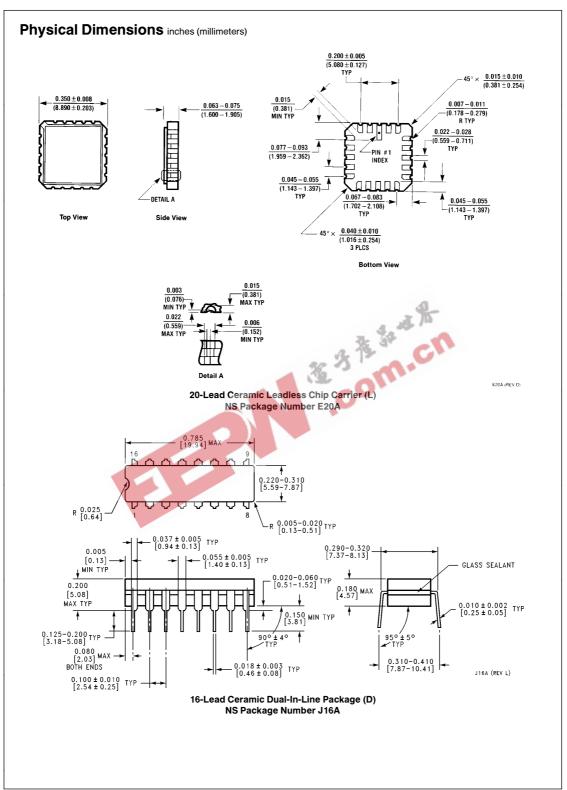
AC Electrical Characteristics

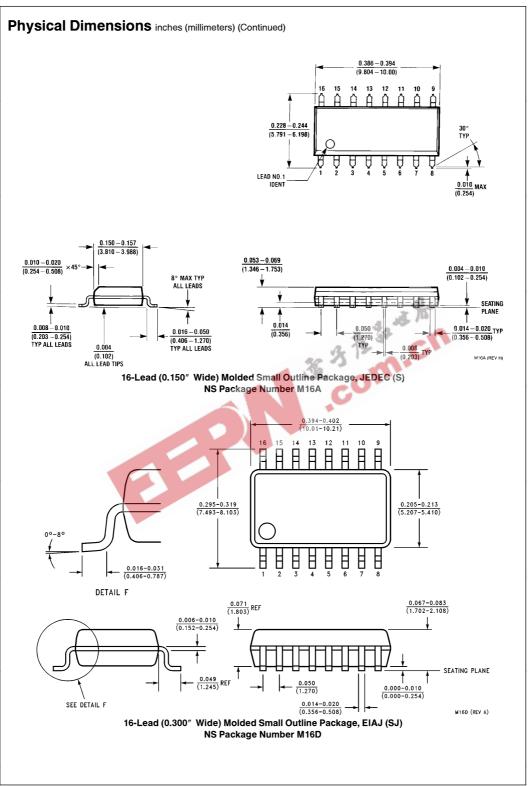
		$74F$ $T_{A} = +25^{\circ}C$ $V_{CC} = +5.0V$ $C_{L} = 50 \text{ pF}$			54	4F	74F		
Symbol	Parameter				T _A , V _{CC} = Mil C _L = 50 pF		T _A , V _{CC} = Com C _L = 50 pF		Units
		Min	Тур	Max	Min	Max	Min	Max	
f _{max}	Maximum Clock Frequency	100	125		75		90		MHz
t _{PLH} t _{PHL}	Propagation Delay CP_U or CP_D to \overline{TC}_U or \overline{TC}_D	4.0 3.5	7.0 6.0	9.0 8.0	4.0 3.5	10.5 9.5	4.0 3.5	10.0 9.0	ns
t _{PLH}	Propagation Delay CP _U or CP _D to Q _n	4.0 5.5	6.5 9.5	8.5 12.5	4.0 5.5	10.0 14.0	4.0 5.5	9.5 13.5	ns
t _{PLH}	Propagation Delay P _n to Q _n	3.0 6.0	4.5 11.0	7.0 14.5	3.0 6.0	8.5 16.5	3.0 6.0	8.0 15.5	ns
t _{PLH}	Propagation Delay PL to Q _n	5.0 5.5	8.5 10.0	11.0 13.0	5.0 5.5	13.5 15.0	5.0 5.5	12.0 14.0	ns
t _{PHL}	Propagation Delay MR to Q _n	6.5	11.0	14.5	6.5	16.0	6.5	15.5	
t _{PLH}	Propagation Delay MR to TC _U	6.0	10.5	13.5	6.0	15.0	6.0	14.5	ns
t _{PHL}	Propagation Delay MR to TC _D	7.0	11.5	14.5	7.0	16.0	7.0	15.5	
t _{PLH}	Propagation Delay PL to TC _U or TC _D	7.0 7.0	12.0 11.5	15.5 14.5	7.0 7 .0	18.5 17.5	7.0 7.0	16.5 15.5	ns
t _{PLH}	Propagation Delay P_n to \overline{TC}_D or \overline{TC}_D	7.0 6.5	11.5 11.0	14.5 1 4.0	7.0 6.5	16.5 16.5	7.0 6.5	15.5 15.0	ns

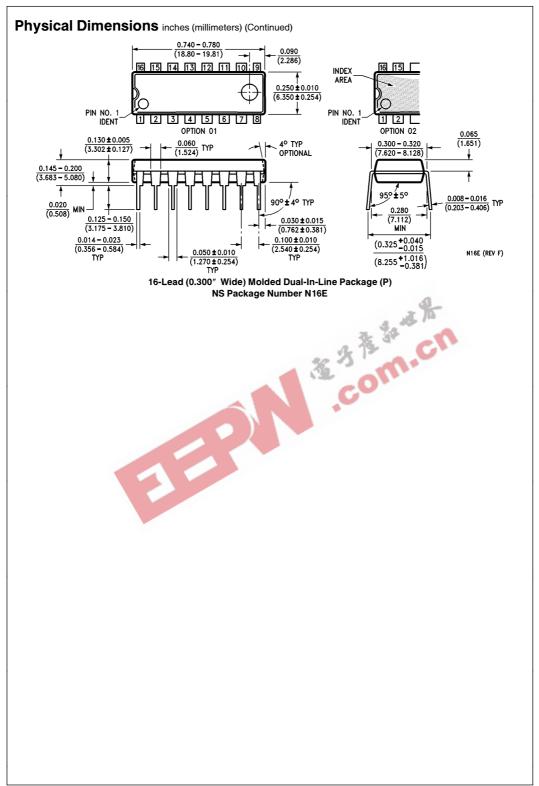
AC Operating Requirements

	Parameter	$74F$ $T_A = +25^{\circ}C$ $V_{CC} = +5.0V$		54	F	74F T _A , V _{CC} = Com		Units
Symbol				T _A , V _{CC}	; = Mil			
		Min	Max	Min	Max	Min	Max	
t _s (H) t _s (L)	Setup Time, HIGH or LOW P _n to PL	4.5 4.5		6.0 6.0		5.0 5.0		ns
t _h (H) t _h (L)	Hold Time, HIGH or LOW P _n to P L	2.0 2.0		2.0 2.0		2.0 2.0		
t _w (L)	PL Pulse Width, LOW	6.0		7.5		6.0		ns
t _w (L)	CP _U or CP _D Pulse Width, LOW	5.0		7.0		5.0		ns
t _w (L)	CP _U or CP _D Pulse Width, LOW (Change of Direction)	10.0		12.0		10.0		ns
t _w (H)	MR Pulse Width, HIGH	6.0		6.0		6.0		ns
t _{rec}	Recovery Time PL to CP _U or CP _D	6.0		8.0		6.0		ns
t _{rec}	Recovery Time MR to CP _U or CP _D	4.0		4.5		4.0		ns

Ordering Information The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows: <u>74F</u> <u>192</u> Temperature Range Family - Special Variations Special Variations X = Devices shipped in 13" reels QB = Military grade with environmental and burn-in processing shipped 74F = Commercial 54F = Military Device Type in tubes Package Code Temperature Range C=Commercial (0°C to +70°C) P = Plastic DIP D = Ceramic DIP $M = Military (-55^{\circ}C to + 125^{\circ}C)$ F = Flatpak L = Leadless Ceramic Chip Carrier (LCC) S = Small Outline SOIC JEDEC SJ = Small Outline SOIC EIAJ







Physical Dimensions inches (millimeters) (Continued) $\frac{0.050 - 0.080}{(1.270 - 2.032)}$ 0.371 - 0.390(9.423 - 9.906) $\frac{0.050 \pm 0.005}{(1.270 \pm 0.127)} \text{ TYP}$ 0.007 - 0.0180.004 - 0.006 $\frac{0.030}{(0.102-0.152)}$ TYP (0.178 - 0.457)-0.000 MIN TYP 0.250 - 0.370 (6.350 - 9.398)0.300 0.245 - 0.275(7.620)(6.223 - 6.985)MAX GLASS * 0.008 - 0.012 $\overline{(0.203 - 0.305)}$ DETAIL A PIN NO. 1 0.250 - 0.370DETAIL A IDENT (6.350 - 9.398)0.026 - 0.040(0.660 - 1.016)(0.381 - 0.482)16-Lead Ceramic Flatpak (F) NS Package Number W16A

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